SFT1443

Power MOSFET 100V, 225mΩ, 9A, Single N-Channel

Features

- High Speed Switching
- ESD Diode-Protected Gate
- Low Gate Charge
- Pb-free, Halogen-free and RoHS Compliance

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter		Symbol	Value	Unit
Drain to Source Voltage		VDSS	100	V
Gate to Source Voltage		VGSS	±20	V
Drain Current (DC)		ID	9	А
Drain Current PW≤10μs, duty cycle≤1%		I _{DP}	36	А
Power Dissipation			1.0	W
	Tc=25°C	PD	19	W
Junction Temperature		Tj	150	°C
Storage Temperature		Tstg	-55 to +150	°C

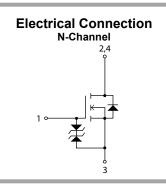
Thermal Resistance Ratings

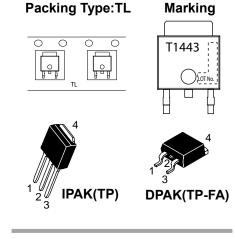
Parameter	Symbol	Symbol Value	
Junction to Case Steady State	R _θ JC	6.58	0000
Junction to Ambient *1	R _{θJA}	125	°C/W

Note : *1 Insertion mounted

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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ORDERING INFORMATION

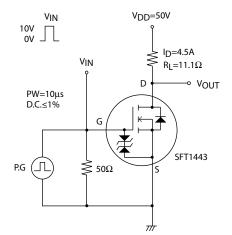
See detailed ordering and shipping information on page 6 of this data sheet.

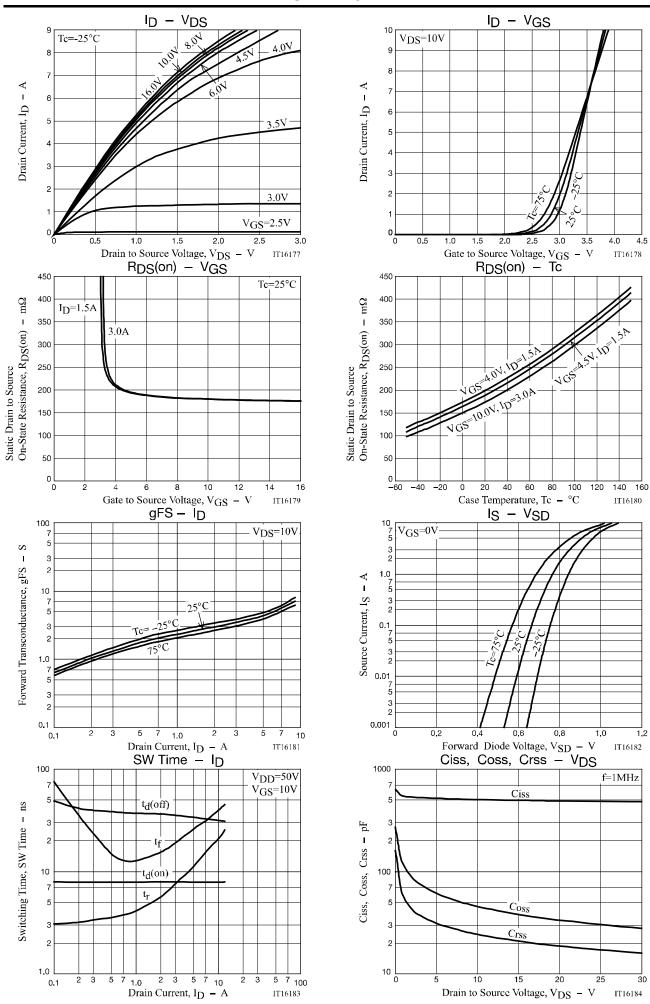
Electrical Characteristics at $Ta = 25^{\circ}C$

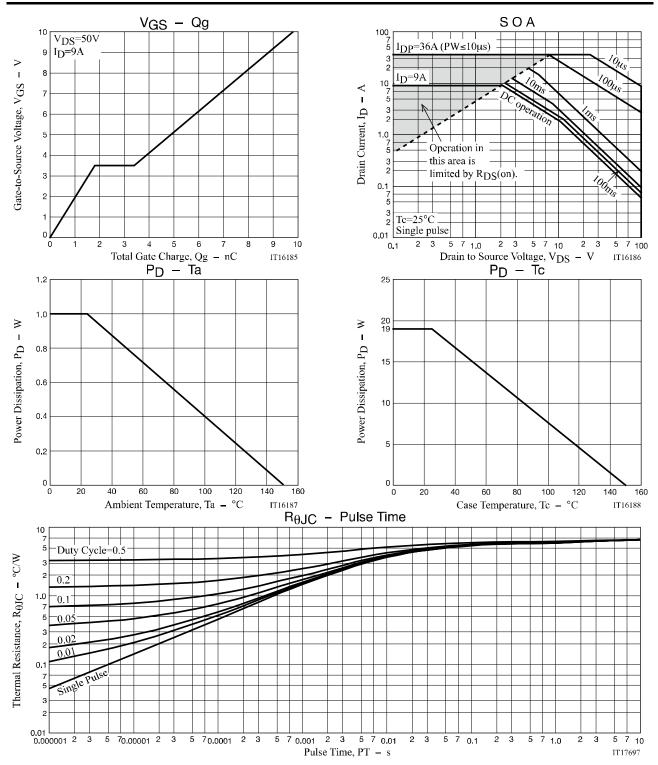
	0			Value		
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	100			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =100V, V _{GS} =0V			1	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =10V, I _D =1mA	1.5		2.6	V
Forward Transconductance	9FS	V _{DS} =10V, I _D =4.5A		4		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =3A, V _{GS} =10V		180	225	mΩ
	R _{DS} (on)2	I _D =1.5A, V _{GS} =4.5V		195	275	mΩ
	R _{DS} (on)3	ID=1.5A, VGS=4V		205	290	mΩ
Input Capacitance	Ciss			490		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		34		pF
Reverse Transfer Capacitance	Crss			19		pF
Turn-ON Delay Time	t _d (on)			8		ns
Rise Time	tr			10		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		34		ns
Fall Time	tf			24		ns
Total Gate Charge	Qg			9.8		nC
Gate to Source Charge	Qgs	V _{DS} =50V, V _{GS} =10V, I _D =9A		1.8		nC
Gate to Drain "Miller" Charge	Qgd	1		1.6		nC
Forward Diode Voltage	VSD	IS=9A, VGS=0V		1.03	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit







Package Dimensions SFT1443-TL-H/ SFT1443-TL-W

DPAK/TP-FA

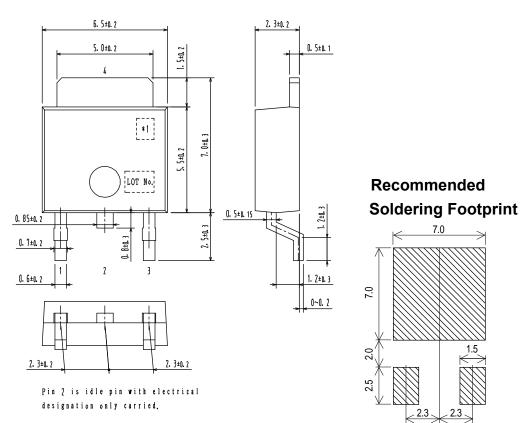
unit : mm





3:Source

4:Drain



*1:Lot indication

7.0

1.5

<u>_2</u>.3

Package Dimensions

SFT1443-H/ SFT1443-W 6. 5±0. 2 2. 3±0. 2 **IPAK/TP** 5. O±0. 2 0. 5±0. 1 1. 5±0. 2 Unit : mm 4 | *1 | 7.0±0.3 5. 5±0. 2 LOT No. 1:Gate 0.85±0.2 2:Drain 0. 7±0. 2 1. 2±0. 1 3:Source 1. 6±0. 2 0. 8±0. 1 4:Drain 5±0.5 0.6±0.2 0. 5±0. 1 2 3 Π

2. 3±0. 2

2. 3±0.2

*1:Lot indication

Ordering & Package Information

Device	Package	Shipping	Note	
SFT1443-H	IPAK(TP)		Pb-Free and Halogen Free	
SFT1443-W	SC-64,TO-251	500pcs. / bag		
SFT1443-TL-H	DPAK(TP-FA)	700pcs. / reel		
SFT1443-TL-W	SC-63,TO-252			

Note on usage : Since the SFT1443 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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